International Rectifier

12TQ... 12TQ...S

SCHOTTKY RECTIFIER

15 Amp

 $I_{F(AV)} = 15Amp$ $V_R = 35 \text{ to } 45V$

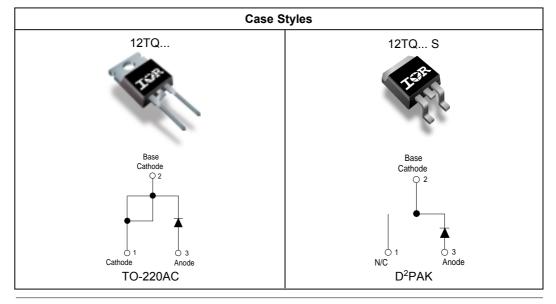
Major Ratings and Characteristics

Characteristics	12TQ	Units
I _{F(AV)} Rectangular waveform	15	А
V _{RRM} range	35 to 45	V
I _{FSM} @tp=5 µs sine	990	А
V _F @15 Apk, T _J = 125°C	0.50	V
T _J range	-55 to 150	°C

Description/ Features

The 12TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150° C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	12TQ035	12TQ040	12TQ045
V _R Max. DC Reverse Voltage (V)			
V _{RWM} Max. Working Peak Reverse Voltage (V)	35	40	45

Absolute Maximum Ratings

	Parameters	12TQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current *See Fig. 5	15	Α	50% duty cycle @ T _C = 120° C, r	ectangular wave form
I _{FSM}	Max. Peak One Cycle Non-Repetitive	990	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and
	Surge Current * See Fig. 7	250		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non-Repetitive Avalanche Energy	16	mJ	T _J =25 °C, I _{AS} =2.4 Amps, L=5.5 mH	
I _{AR}	Repetitive Avalanche Current	2.4	Α	Current decaying linearly to zero in 1 µsec	
				Frequency limited by T _J max. V _j	_A =1.5xV _R typical

Electrical Specifications

	Parameters	12TQ	Units		Conditions	
V_{FM}	Max. Forward Voltage Drop (1)	0.56	V	@ 15A	T ₁ = 25 °C	
	* See Fig. 1	0.71	V	@ 30A	1 _J = 23 0	
		0.50	V	@ 15A	T _. = 125 °C	
		0.64	V	@ 30A	1, 128 8	
I _{RM}	Max. Reverse Leakage Current (1)	1.75	mA	T _J = 25 °C	V _P = rated V _P	
	* See Fig. 2	70	mA	T _J = 125 °C	V _R Tates V _R	
C _T	Max. Junction Capacitance	900	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25 °C		
L _S	Typical Series Inductance	8.0	nH	Measured lead to lead 5mm from package body		
dv/dt		10000	V/ µs			

⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters		12TQ	Units	Conditions
T _J	Max. Junction Temperature	Range	-55 to 150	°C	
T _{stg}	Max. Storage Temperature Range		-55 to 150	°C	
R _{thJC}	Max. Thermal Resistance Juto Case	inction	2.0	°C/W	DCoperation *See Fig. 4
R _{thCS}	Typical Thermal Resistance, Case to Heatsink		0.50	°C/W	Mounting surface, smooth and greased
wt	ApproximateWeight		2(0.07)	g(oz.)	
Т	MountingTorque	Min.	6(5)	Kg-cm	
		Max.	12(10)	(lbf-in)	

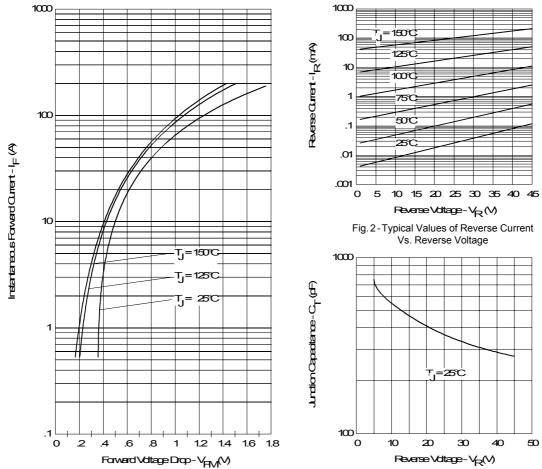


Fig. 1-Maximum Forward Voltage Drop Characteristics

Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

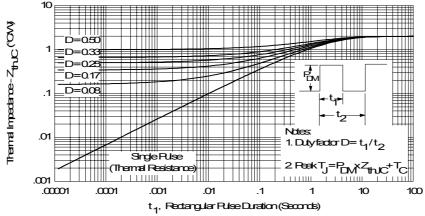


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

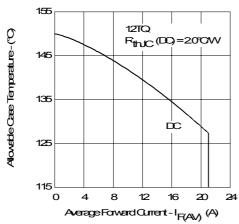


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

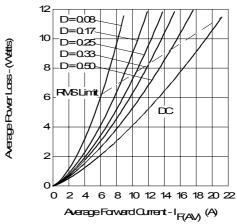


Fig. 6 - Forward Power Loss Characteristics

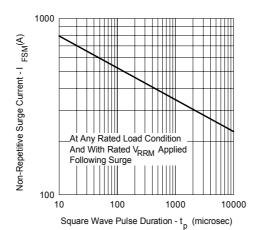


Fig. 7 - Maximum Non-Repetitive Surge Current

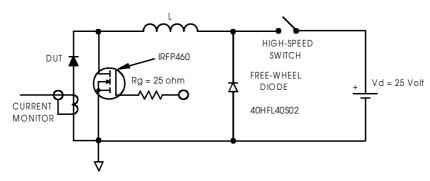
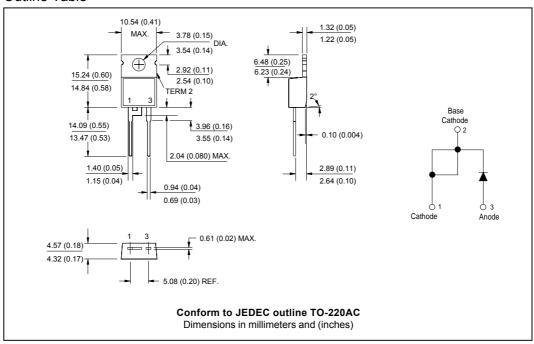
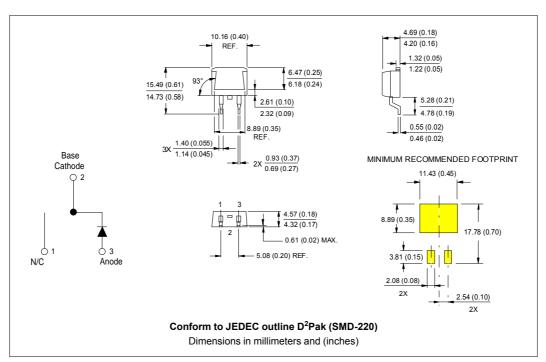


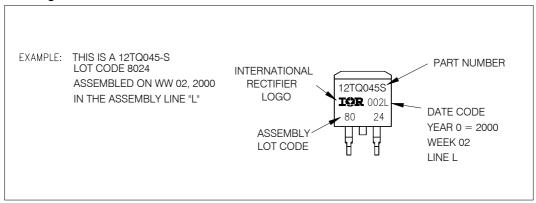
Fig. 8 - Unclamped Inductive Test Circuit

Outline Table

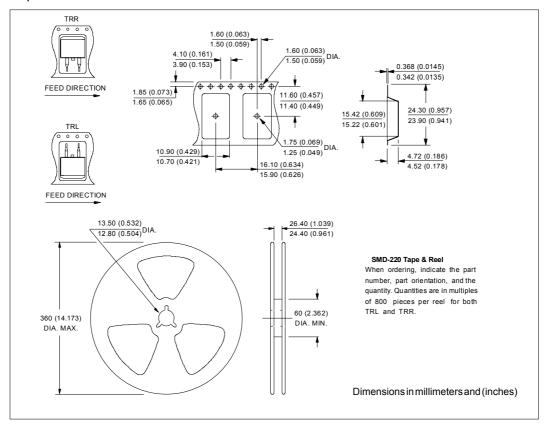




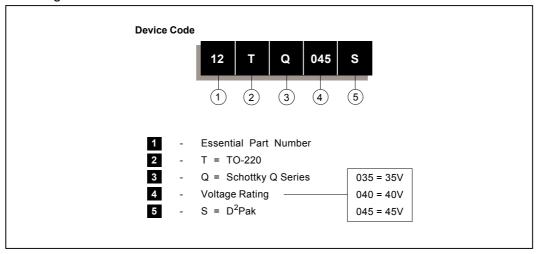
Marking Information



Tape & Reel Information



Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 12/01